

Features

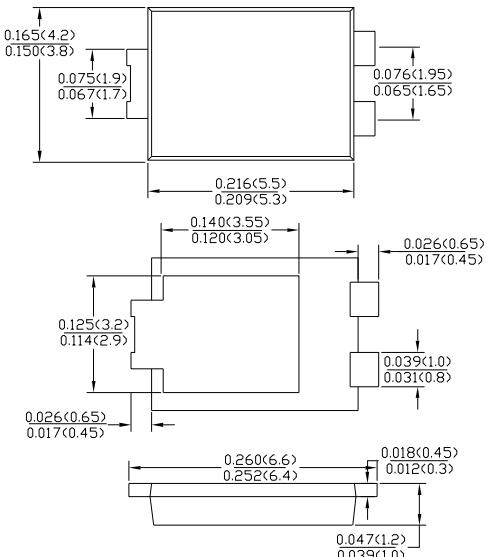
- Bypass Diodes for Solar Panels
- Maximum Junction Temperature 200°C
- High Thermal Reliability
- Patented Super Barrier Rectifier Technology
- High Forward Surge Capability
- Ultra Low Power Loss, High Efficiency
- Excellent High Temperature Stability

Mechanical Data

- Case: TO-277 Molded Plastic "Green" Molding Compound
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.093 grams (approx.)
- Mounting Position: Any
- Marking: Type Number
- Lead Free: For RoHS/Lead Free Version



TO-277



Maximum Ratings and Electrical Characteristics $\text{@} T_A=25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	MBR1045ULPS	Unit
Peak Repetitive Reverse Voltage	V_{RRM}		
Working Peak Reverse Voltage	VR_{WM}	45	V
DC Blocking Voltage	V_R		
RMS Reverse Voltage	$VR(\text{RMS})$	32	V
Average Rectified Output Current (Note 1)	I_o	10.0	A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	150	A
Forward Voltage Drop $\text{@} I_F = 10\text{A}, T_j = 25^\circ\text{C}$	V_{FM}	0.53	V
Peak Reverse Current $\text{@} V_F = 45\text{V}, T_j = 25^\circ\text{C}$ At Rated DC Blocking Voltage $\text{@} V_F = 45\text{V}, T_j = 100^\circ\text{C}$	I_{RM}	0.3 15	mA
Typical Thermal Resistance Junction to Ambient (Note 2) (Note 3)	R_{0JA}	73 31	$^\circ\text{C}/\text{W}$
Operating Temperature Range $\text{@} V_R \leq 80\% V_{RRM}$ DC Forward Mode	T_j	-55 to +150	$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-55 to +1	$^\circ\text{C}$

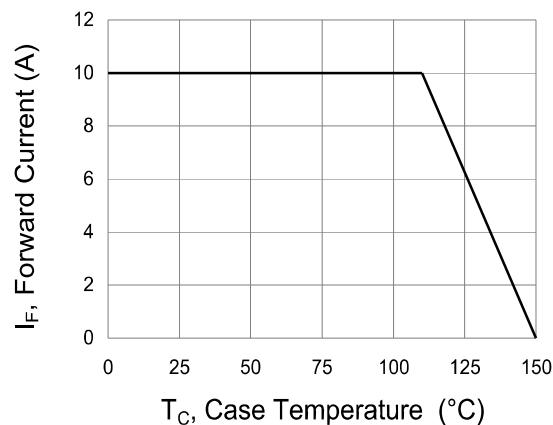


Fig. 1 Forward Power Dissipation

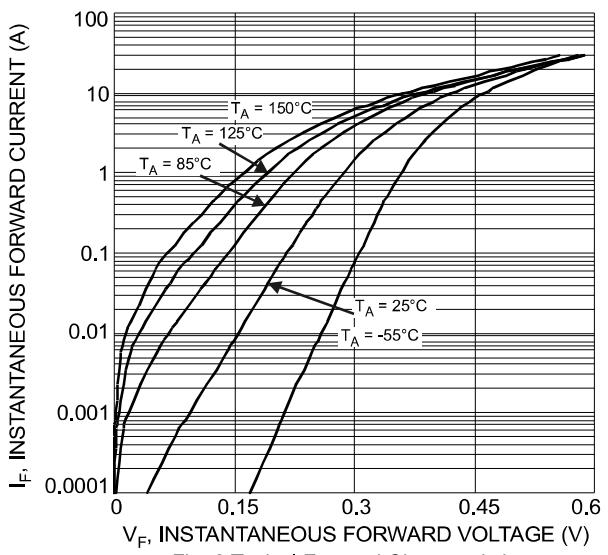


Fig. 2 Typical Forward Characteristics

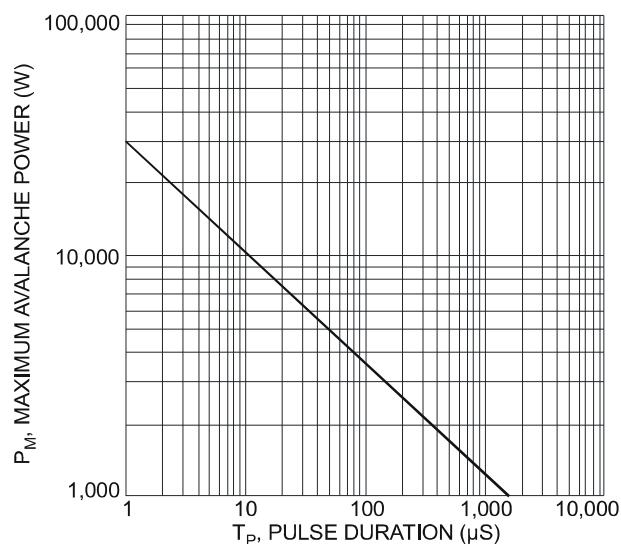


Fig. 3 Maximum Avalanche Power